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PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of: Leonard J. Olmer, et al.

Serial No.: 10/675,575

Filed: September 30, 2003

Title: IN-SITU REMOVAL OF SURFACE IMPURITIES PRIOR TO ARSENIC-DOPED POLYSILICON DEPOSITION IN THE FABRICATION OF A HETEROJUNCTION BIPOLAR TRANSISTOR

Grp./A.U.: 1746

Examiner: Zeinab El Arini

Confirmation No. 9967

For:

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed with United States Patent and trademark Office on:

\_\_ September 1, 2006 \_\_ (Date)

Karen Vertz  
(Printed or typed name of person signing the certificate)

/Karen Vertz/  
(Signature of the person signing the certificate)

Sir:

**PRELIMINARY AMENDMENT UNDER 37 C.F.R. § 1.114**

Before examination of the above-identified application, please amend it as follows: